

# Effect of dipole location on profile properties of symmetric surface plasmon polariton mode in Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide

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**Abstract** This study uses a dipole embedded in Al<sub>2</sub>O<sub>3</sub> layer to excite a symmetric surface plasmon polariton (SPP) mode in Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide to investigate its profile properties by using finite-difference time-domain (FDTD) method. The excited dipole decay radiatively direct near-field coupling to SPP mode owing to thin Al<sub>2</sub>O<sub>3</sub> layer of 100 nm. The effects of electric and magnetic field intensity profiles and decay length have been considered and characterized. It is found that dipole location is an important factor to influence the horizontal and vertical profile properties of symmetric SPP mode in Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide. The amplitudes of electric and magnetic field intensity and the wavelengths of metal-insulator-metal (MIM) SPP resonance mode can be tuned by varying dipole location. The horizontal and vertical decay lengths are 19 and 24 nm, respectively. It is expected that the Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide structure is very useful for the practical applications of designing a SPP source.

**Keywords** waveguide, surface plasmon polariton (SPP), profile properties

## 1 Introduction

Surface plasmon polariton (SPP) is electromagnetic waves coupled to free electron oscillation on metal surface and propagates along the metal-dielectric interface with the amplitudes decaying into both sides exponentially [1]. One of the most attractive aspects of SPP is the way in which they help concentrate and channel light beyond diffraction limit [2]. Some novel photonic devices based on SPP, such

as waveguide [3], reflector [4] and beam splitters [5], have gained an increasing research interest recently. Of available SPP waveguides, metal-insulator-metal (MIM) configuration [6–10] is very promising for compact photonic integration. This is the reason that such a MIM geometry serves as a plasmonic slot waveguide, “squeezing” the SPP field into the dielectric core [11]. Until now, different MIM SPP waveguide have been demonstrated, such as various passive (e.g., filters [12]) and active plasmonic devices (e.g., emitters [13]).

In recent years, the excitation of SPP has been a promising way to squeeze optical energy in nanometric cross section [14]. There are a lot of literatures on SPP excitation, such as electron-induced [15] or light-induced [16] SPP excitation. As the insulator layer of MIM waveguide is too thin to support photonic modes, the excited dipole decay radiatively only by direct near-field coupling to plasmonic transverse magnetic (TM) modes. So, the MIM waveguide geometry is particularly promising for light-induced SPP excitation. Most recently, the SPP sources based on MIM waveguide have been demonstrated experimentally, including an electrical source of SPP using organic semiconductors by Koller et al. [17] and using silicon nanocrystals embedded in Al<sub>2</sub>O<sub>3</sub> by Walters et al. [18]. Although the pioneering work [18] already observed and testified that the SPP mode can occur in the MIM waveguide under a certain condition, they did not offer physical origin of such a MIM SPP mode theoretically and an exact condition for its existence. Moreover, the physical origin of such a MIM SPP mode and the exact condition for its existence have important theoretical reference value for the design of a SPP source. However, these vital electromagnetic field profile properties of SPP mode have been left untouched. It is also noticed that the numerical study of the light (dipole)-induced SPP excitation is an area in urgent need of further work.

In this paper, we present the first study of horizontal and vertical profile properties of symmetric SPP mode in Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide, which only supports tightly confined coupled SPP mode within the thin Al<sub>2</sub>O<sub>3</sub> layer by using finite-difference time-domain (FDTD) method. The aim of this paper is to give a numerical analysis of light (dipole)-induced SPP excitation. Attention will be focused on the fundamental physics and the electromagnetic field profile properties of MIM SPP mode. The simulation results show that both the amplitudes of electric and magnetic field intensity and the wavelengths of MIM SPP resonance mode can be tuned by varying dipole location, owing to the role of coupling between dipole and Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide. This phenomenon may provide guidance in designing a SPP source by using Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide structure.

## 2 Theoretic model and FDTD modeling method

MIM waveguide is composed of two identical Au films (200 nm) separated by an insulator layers Al<sub>2</sub>O<sub>3</sub> (100 nm), and the horizontal length of the MIM waveguide is infinite, as shown in Fig. 1. When the width ( $w$ ) of dielectric layer is reduced below the diffraction limit, conventional guiding modes cannot exist. In this case, a TE 90 polarization incident light (dipole) will be transformed into the coupled SPP on the metal surfaces and propagates along the waveguide. The dispersion relation of the SPP in the MIM waveguide can be deduced from the Maxwell equations as [19]

$$\frac{p\epsilon_d}{k\epsilon_m} = \frac{1 - e^{kw}}{1 + e^{kw}}, \quad (1)$$

where

$$k = k_0 \sqrt{\left(\frac{\beta_{\text{SPP}}}{k_0}\right)^2 - \epsilon_d}, \quad (2)$$

$$p = k_0 \sqrt{\left(\frac{\beta_{\text{SPP}}}{k_0}\right)^2 - \epsilon_m}, \quad (3)$$

and

$$\beta_{\text{SPP}} = n_{\text{eff}} k_0, \quad (4)$$

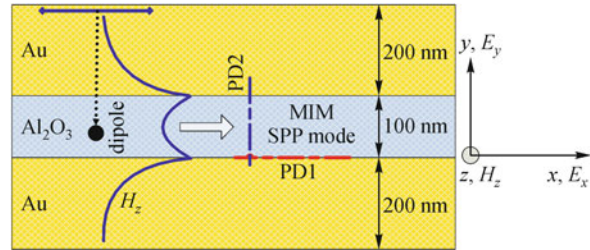
where  $k_0$  is the wave vector in free space,  $\beta_{\text{SPP}}$  and  $n_{\text{eff}}$  are the complex propagation constant and the effective refractive index of SPP, respectively.  $\epsilon_m$  and  $\epsilon_d$  are the relative dielectric constant of the metal and the dielectric material, respectively. Gold for the metallic cladding layers is characterized by the Drude model [20]

$$\epsilon_m = 1 - \frac{\omega_p^2}{\omega(\omega + i\gamma)}, \quad (5)$$

where  $\omega_p = 1.2 \times 10^{16}$  Hz and  $\gamma = 1.2 \times 10^{14}$  Hz are the bulk plasma and damping frequencies, respectively, and Al<sub>2</sub>O<sub>3</sub> with refractive index  $n_d = 1.7$ . As Al<sub>2</sub>O<sub>3</sub> layer is too thin (100 nm) to support photonic modes, the excited dipole decay radiatively only by direct near-field coupling to a symmetric SPP mode, which is highly confined within the insulating region. The characteristic equation of symmetric SPP mode is given by [21]:

$$\frac{\kappa_m}{\epsilon_m} + \frac{\kappa_d}{\epsilon_d} \tanh\left(\frac{1}{2}\kappa_d w\right) = 0, \quad (6)$$

where  $\kappa_m = \sqrt{\beta_{\text{SPP}}^2 - \epsilon_m}$  and  $\kappa_d = \sqrt{\beta_{\text{SPP}}^2 - \epsilon_d}$  denote the transverse wavenumber of the plasmonic mode in the metal and dielectric, respectively.



**Fig. 1** Schematic structure of proposed Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide composed of two identical Au films separated by an insulator layers Al<sub>2</sub>O<sub>3</sub>, and a dipole is embedded in Al<sub>2</sub>O<sub>3</sub> layer to excite a MIM SPP mode for forward propagating

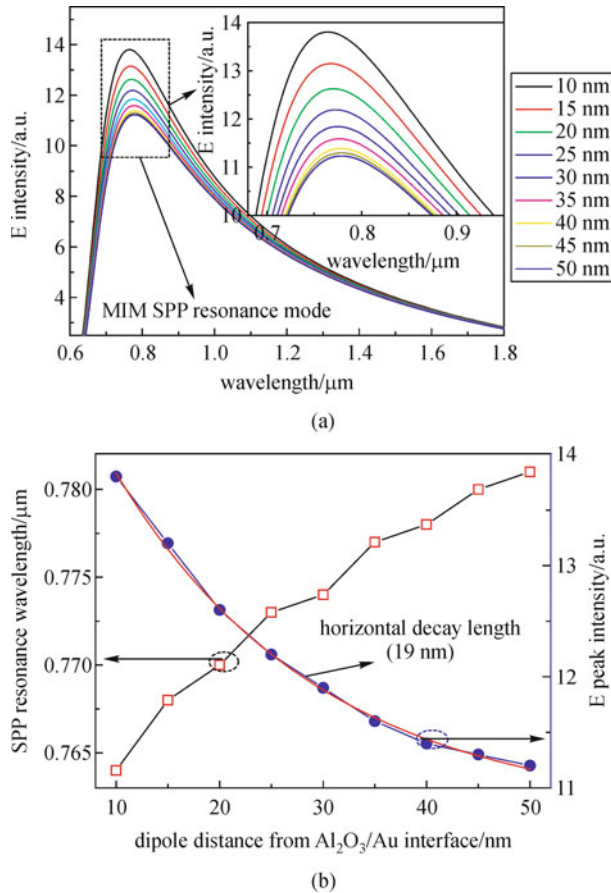
Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide two dimensional (2D) structure is designed and modeled by a commercial FDTD package<sup>1)</sup> that supports ununiform meshing and eigenmode calculation. Spatial mesh cells are set to  $\Delta x = \Delta y = 5$  nm and the time step is taken as  $\Delta t = \Delta s/2c = 8.3333 \times 10^{-18}$  s. The 2D FDTD method with perfectly matched layer (PML) as boundary condition is used in this work. The fundamental TM mode ( $E_x; E_y; H_z$ ) of the Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide is excited by a dipole source being located in the intermediate Al<sub>2</sub>O<sub>3</sub> layer and the mesh grid size is set to 1 nm in order to maintain convergence. And then the MIM SPP mode is excited and two different power monitors PD1 (horizontal) and PD2 (vertical) are set to detect the incident power A1. In this simulation experiment, the dipole in the proposed waveguide structure is located in Al<sub>2</sub>O<sub>3</sub> at distances of 10, 15, 20, 25, 30, 35, 40, 45 and 50 nm from the bottom Al<sub>2</sub>O<sub>3</sub>/Au interface and the thickness of Al<sub>2</sub>O<sub>3</sub> is fixed at 100 nm. It is obvious that there is a symmetric plasmonic H<sub>z</sub> mode (as shown in Fig. 1) supported in the MIM SPP mode, which arises from an asymmetric coupling of SPP at inner interfaces of Au

1) The commercial software FDTD solutions was employed for the numerical simulation

layers. The simulated electric field and magnetic field intensity profiles of MIM SPP mode with different MIM geometry ( $t_{\text{Au(top)}} = t_{\text{Au(bottom)}} = 200$  nm,  $w = 100$  nm) by changing the dipole distance are shown in Figs. 2(a) and 3(a).

### 3 Simulation results and discussion

To study the influence of dipole location on the performance of symmetric SPP mode in Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide, the horizontal profiles of the electric field and magnetic field intensity profiles are calculated for the structures as shown in Figs. 2(a) and 3(a). Figure 2(a) shows the horizontal profiles of the electric field intensity ( $i_E^x$ ) of MIM SPP mode at the interface of Al<sub>2</sub>O<sub>3</sub>/Au along the  $x$ -axis for the frequency corresponding to the free space wavelength of dipole from 0.6 to 1.8  $\mu\text{m}$ . In addition, the amplified part of MIM SPP resonance mode is shown in the inset. By varying dipole distances from 10 to 50 nm in steps of 5 nm with the thickness of Al<sub>2</sub>O<sub>3</sub> layer of 100 nm,

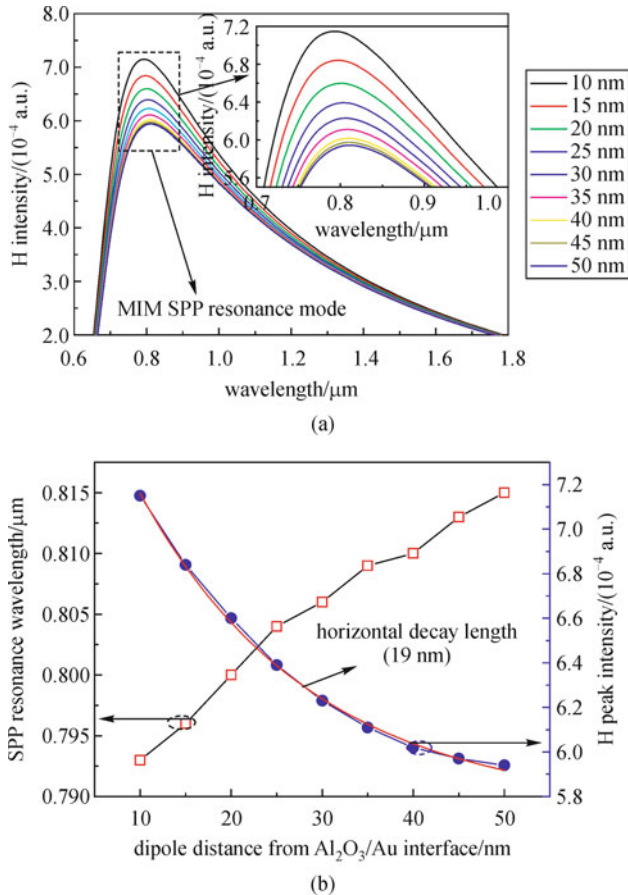


**Fig. 2** (a) Horizontal profiles of electric field (E) intensity at bottom Al<sub>2</sub>O<sub>3</sub>/Au interface as a function of dipole distance; (b) electric (E) field peak intensity and SPP resonance wavelength as function of dipole distance

$i_E^x$  is decreased, due to the different coupling strengths between dipole and Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide. This is the reason that dipole distance is critical to the SPP coupling strength. As the dipole distance gets larger, the SPP coupling strength becomes weaker, leading to decrease of  $i_E^x$ . In addition, we have plotted two curves based on the data from  $i_E^x$  of MIM SPP resonance mode.  $i_E^x$  and SPP resonance wavelength ( $\lambda_{\text{SPP}}$ ) as a function of dipole distance are shown in Fig. 2(b). It is clearly seen that  $\lambda_{\text{SPP}}$  is red shifted consistently and  $i_E^x$  is exponential decay. The exponential relationship between  $i_E^x$  and the dipole distance ( $d$ ) becomes obvious.  $i_E^x$  can be fitted using an exponential function to determine the horizontal decay properties of SPP mode along the  $x$ -axis. The fitting curve of the FDTD simulation results for  $i_E^x$  is  $i_E^x = 5\exp(-d/19) + 11$ . So, the horizontal decay length is 19 nm. The physical concept of the horizontal decay length arises from the fact that the change of dipole distance resulting in  $i_E^x$  being diminished by  $1/e$ . This is very useful for designing an SPP source with a desirable luminescence center (19 nm) by merely adjusting dipole distance to make best SPP coupling between top and bottom Au films in Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide. The redshift of  $\lambda_{\text{SPP}}$  with the augment of dipole distances results from the asymmetric coupling of SPP between dipole and Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguide. It is the reason that the asymmetric coupling of SPP becomes strong when the location of dipole is near the middle position.

Figures 3(a) shows the horizontal profiles of the magnetic field intensity ( $i_H^x$ ) of MIM SPP mode at the interface of Al<sub>2</sub>O<sub>3</sub>/Au along the  $x$ -axis.  $i_H^x$  is also decreased. As the dipole distance gets larger, the SPP coupling strength becomes weaker which results in a decrease of  $i_H^x$ ,  $i_E^x$  and  $\lambda_{\text{SPP}}$  as a function of dipole distance are shown in Fig. 3(b). It is clearly seen that  $\lambda_{\text{SPP}}$  is red shifted consistently and  $i_H^x$  is exponential decay. The fitting curve of the FDTD simulation results for  $i_H^x$  is  $i_H^x = 2.4 \times 10^{-4}\exp(-d/19) + 5.7 \times 10^{-4}$ . The horizontal decay length is 19 nm.

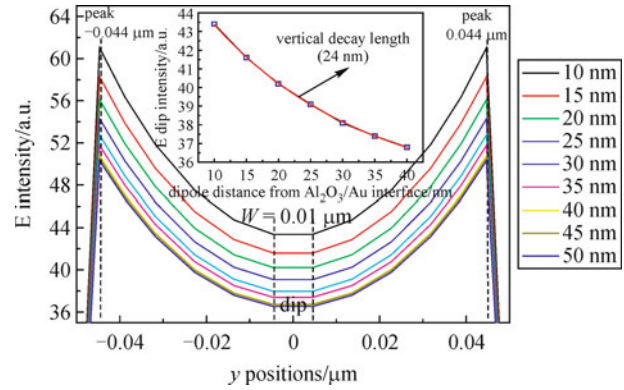
To achieve an in-depth understanding of the effect of dipole distance on the profile properties of MIM SPP mode, we used a 2D FDTD numerical simulation to model the vertical profiles of the electric field and magnetic field intensity of the corresponding MIM SPP resonance mode, as shown in Figs. 4 and 5 along the  $y$ -direction. Figure 4 shows the vertical profiles of the electric field intensity ( $i_E^y$ ) of the corresponding MIM SPP resonance mode along the  $y$ -axis.  $i_E^y$  is decreased exponentially with increasing the dipole distance from 10 to 50 nm in steps of 5 nm, due to the SPP coupling strength becoming weaker. The MIM SPP resonance mode effect clearly appears at vertical profiles along the  $y$ -axis (peak and dip). Furthermore, the positions of peaks and dips in the electric field intensity profiles are almost not affected, which are centered around  $\pm 0.044$  and  $0$   $\mu\text{m}$ , respectively, and the width between dips



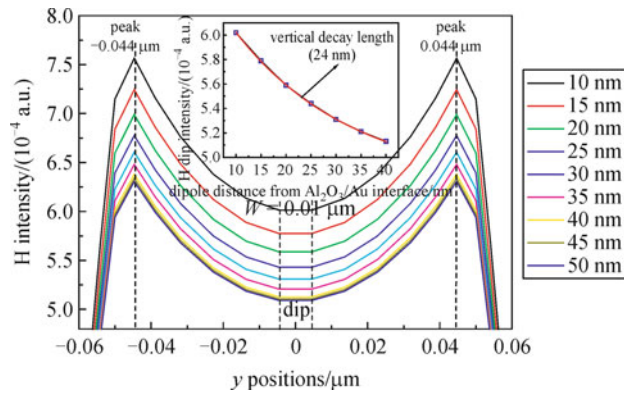
**Fig. 3** (a) Horizontal profiles of magnetic field (H) intensity at bottom  $\text{Al}_2\text{O}_3/\text{Au}$  interface as function of dipole distance; (b) magnetic field (H) peak intensity and SPP resonance wavelength as function of dipole distance

is  $0.01 \mu\text{m}$ . In addition, the exponential relationship between  $i_E^y$  and  $d$  becomes obvious as shown in the inset.  $i_E^y$  can be fitted using an exponential function to determine the vertical decay properties of SPP mode in the  $\text{Au}/\text{Al}_2\text{O}_3/\text{Au}$  MIM waveguide along the  $y$ -axis. The fitting curve of the FDTD simulation results for  $i_E^y$  is  $i_E^y = 14\exp(-d/24) + 34$ . So, the vertical decay length is  $24 \text{ nm}$ . The physical concept of the vertical decay length arises from the fact that the change of dipole distance resulting in  $i_E^y$  being diminished by  $1/e$ . This is very useful for the designing a SPP source with a desirable luminescence center ( $24 \text{ nm}$ ) by merely adjusting the locations of dipole to make the coupled SPP mode being more gathered and propagated in  $\text{Al}_2\text{O}_3$  layer.

Figure 5 shows the vertical profiles of the magnetic field intensity ( $i_H^y$ ) of the corresponding MIM SPP resonance mode along the  $y$ -axis.  $i_H^y$  is also decreased exponentially with increasing the dipole distance from  $10$  to  $50 \text{ nm}$  in steps of  $5 \text{ nm}$ , due to the SPP coupling strength becoming weaker. Furthermore, the positions of peaks and dips in the



**Fig. 4** Vertical profiles of electric field (E) intensity of corresponding MIM SPP resonance mode along  $y$ -axis as function of dipole distance. Inset, dependence of electric field dip intensity on dipole distances



**Fig. 5** Vertical profiles of magnetic field (H) intensity of corresponding MIM SPP resonance mode along  $y$ -axis as function of dipole distance. Inset, dependence of magnetic field dip intensity on dipole distances

magnetic field intensity profiles are almost not affected, which are centered around  $\pm 0.044$  and  $0 \mu\text{m}$ , respectively, and the width between dips is  $0.01 \mu\text{m}$ . The exponential relationship between  $i_H^y$  and  $d$  becomes obvious as shown in the inset. The fitting curve of the FDTD simulation results for  $i_H^y$  is  $i_H^y = 1.9 \times 10^{-4}\exp(-d/24) + 4.8 \times 10^{-4}$ . So, the vertical decay length is  $24 \text{ nm}$ .

## 4 Conclusions

In conclusion, the horizontal and vertical profile properties of symmetric SPP mode in  $\text{Au}/\text{Al}_2\text{O}_3/\text{Au}$  MIM waveguide are investigated by varying dipole location yet the thickness of  $\text{Al}_2\text{O}_3$  layer being fixed at  $100 \text{ nm}$  through the FDTD simulation. Based on the calculated electromagnetic field intensity profile properties, the dipole

location is an important factor to the horizontal and vertical profile properties of symmetric SPP mode. The horizontal profiles of  $i_E^x$  and  $i_H^x$  decrease and  $\lambda_{\text{SPP}}$  are red shifted consistently when the dipole distances increase. The vertical profiles of  $i_E^y$  and  $i_H^y$  are also decreased exponentially with increase of the dipole distances. However the positions of peaks and dips in the electric field and magnetic field intensity are not affected. The horizontal and vertical decay lengths are 19 and 24 nm respectively. It indicated that the resonant coupling effect of SPP plays a crucial role in the Au/Al<sub>2</sub>O<sub>3</sub>/Au MIM waveguide. These properties will undoubtedly facilitate the application of Au/Al<sub>2</sub>O<sub>3</sub>/Au waveguides in designing an SPP source.

**Acknowledgements** This work was supported by the National Natural Science Foundation of China (Grant Nos. 60907024 and 61036011), the New Teachers' Fund for the Doctoral Program of Higher Education (No. 20100001120024), Scientific Research Foundation for the Returned Overseas Chinese Scholars, State Education Ministry.

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